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Sheet 1 of 1

Complete If Known	
Application Number	10/677,614 TBD
Filing Date	10/2/03 ~~Herewith~~
First Named Inventor	Srinivasan Chakravarthi, et al.
Group Art Unit	2813
Examiner Name	~~Yennhu B. Huyh~~
Attorney Docket No.	TI-33161.2

U.S. PATENT DOCUMENTS

Exam. Initials*	Cite No.[1]	U.S. Patent Document Number	U.S. Patent Document Kind Code[2] (if known)	Name of Patentee or Applicant of Cited Doc.	Date of Pub. of Cited Doc. (mm-dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
	AA	6,037,640		Lee	3/14/00	
	AB					
	AC					
	AD					
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FOREIGN PATENT DOCUMENTS

Exam. Initials*	Cite No.[1]	Foreign Patent Document Office[3]	Foreign Patent Document Number[4]	Foreign Patent Document Kind Code[2] (if known)	Name of Patentee or Applicant of Cited Doc.	Date of Pub. of Cited Doc. (mm-dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T[6]
	BA							
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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Exam. Initials*	Cite No.[1]	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T[2]
	CA	P. PACKAN ET AL., "Modeling Solid Source Boron Diffusion for Advanced Transistor Applications" IEEE, IEDM 98, pp. 505-508	
	CB	DANIEL F. DOWNEY ET AL., "Effect of Fluorine on the Diffusion of Boron in Ion Implanted Si" 1998 American Institute of Physics, Vol. 73, Number 9, August 31, 1998, pp. 1263-1265	
	CC		
	CD		
	CE		
	CF		
	CG		

Examiner Signature		Date Considered	12/8/05

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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